

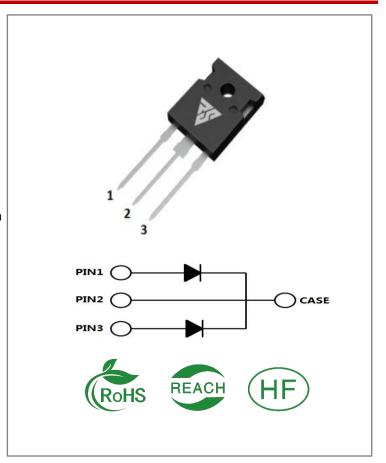
VRRM	IF ( TC≤135℃)	QC
650V	48A	102nC

## **Applications:**

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

#### **Features:**

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on VF
- Temperature-independent Switching
- 175°C Operating Junction Temperature



### **Benefits:**

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

### **Ordering Information**

Part Number	Package	Marking	Packing	Qty.
RSS40120K	TO-247-3	RSS40120K	Tube	30 PCS



# Maximum Ratings (TJ= 25°C unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
VRRM	Repetitive Peak Reverse Voltage	1200	V	TC = 25°C	
VRSM	Surge Peak Reverse Voltage	1200	٧	TC = 25°C	
VR	DC Blocking Voltage	1200	٧	TC = 25°C	
IF	Forward Current	52*22 4*2 20/40	А	TC ≤ 25°C TC ≤ 135°C TC ≤ 146°C	
IFRM	Repetitive Peak Forward Surge Current	180*2	Α	TC = $25^{\circ}$ C, tp =8.3ms, Half Sine Wave	
Ptot	Power Dissipation	230*2	W	TC = 25°C	Fig.3
TC	Maximum Case Temperature	146	$^{\circ}\!$		
TJ,TST G	Operating Junction and Storage Temperature	-55 to175	$^{\circ}\!$		

# **Electrical Characteristics** (TJ= 25℃ unless otherwise specified)

Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note	
VF	Forward Voltage	1.55	1.8	V	IF = 20A, TJ = 25℃	Eia 1	
VF	Forward Voltage	2.2	2.5	V	IF = 20A, TJ = 175°C	Fig.1	
ID	Reverse Current	5	20	^	VR = 1200V, TJ = 25℃	Fig.2	
IR Reverse Current		30	200	μΑ	VR = 1200V, TJ = 175°C	rig.Z	
		1280			VR = 1V, TJ = 25°C, f = 1MHz		
С	Total Capacitance	95	/	рF	VR = 400V, TJ = 25℃, f = 1MHz	Fig.5	
		77			VR = 800V, TJ = 25℃, f = 1MHz		
00	Total Capacitive	51	,	nC	VR =800V,	Fig.4	
QC	Charge	<u> </u>	/	IIC	VK -000V,	Fig.4	

# **Thermal Characteristics** (TJ= 25 °C unless otherwise specified)

Symbol	Parameter	Тур.	Unit	Note
RθJC	Thermal Resistance from Junction to Case	0.65	°C/W	Fig.6



### **Typical Feature Curve**

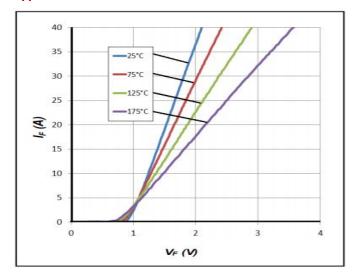


Figure 1. Forward Characteristics

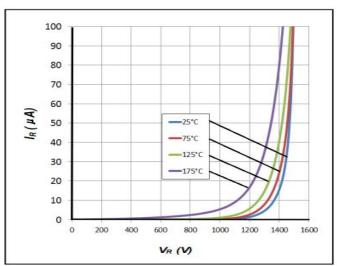


Figure 2. Reverse Characteristics

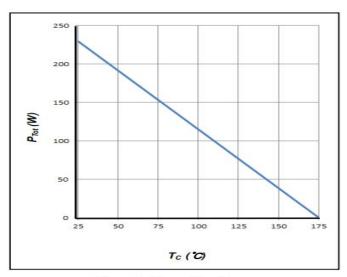


Figure 3. Power Derating

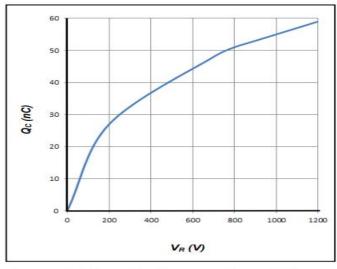


Figure 4. Total Capacitive Charge vs. Reverse Voltage

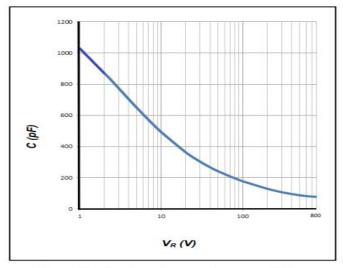


Figure 5. Total Capacitance vs. Reverse Voltage

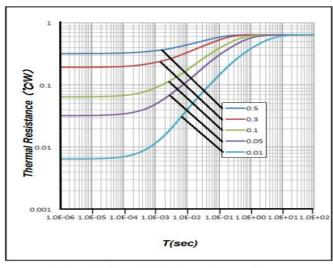
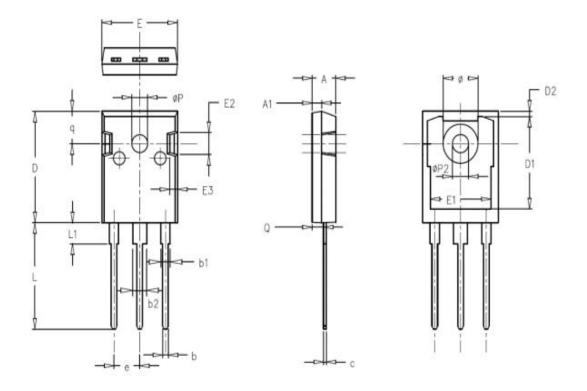


Figure 6. Transient Thermal Impedance

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# Package outline drawing(TO-247-3 Unit: mm)



SYMBOL	MILLIMETERS		NOTES	CVALDOL	MILLIMETERS			N. OTT.	
	N ormal	MIN.	MAX.	N OTES	SYMBOL	Normal	MIN.	MAX.	N OTES
Α	4.98	4.68	5.36		øР	3.66	3.45	3.85	
A 1	1.99	1.90	2.10		e	5.44	BSC	;	
Q	2.41	2.30	2.60		q	6.24	5.99	6.58	
С	0.60	0.48	0.72	,	øP2	3.45	3.24	3.64	
ь	1.20	1.00	1.40		ø	7.14	7.10	7.30	
Ь1	2.07	1.90	2.30		D1	16.56	16.10	17.10	
b2	3.07	2.90	3.30		D2	0.98	0.80	1.36	
D	21.10	20.80	21.80		E1	13.30	13.00	13.52	
E	15.98	15.38	16.20		E2	5.64	5.10	6.10	
L	20.28	19.50	20.50		E3	2.33	1.90	2.70	
L1	4.01	3.75	4.35						



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